

# APPLICATION DATA SHEET

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Attorney Docket Number: PS-70

Application Type: utility

Title of Invention: ESD-Isolation Circuit Driving Gate of Bus-Switch Transistor During  
ESD Pulse Between Two I/O Pins

## Request Not To Publish

*I hereby request that the attached application not be published under 35 U.S.C. 122(b). I hereby certify that the invention disclosed in the attached application has not and will not be the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing.*

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